

# Simultaneous Observation of Silicon and Boron Impurity Behaviors in the Core Region of a Mid-Density LHD Plasma

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Line emissions from both silicon (Si) and boron (B) impurity ions introduced by a single tracer-encapsulated solid pellet (TESPEL) containing silicon hexaboride ( $\text{SiB}_6$ ) powders were successfully observed using the extreme ultraviolet (EUV) spectrometer and charge-exchange spectroscopy (CXS) technique in the Large Helical Device. The CXS diagnostic shows clearly that a hollow radial profile of fully ionized B impurities was created immediately after the TESPEL injection, and such a hollow profile was relaxed with time. At the same time, Li-like emissions from the highly ionized Si impurities were also observed with the EUV spectrometer, SOX-MOS. Therefore, the decay times of these impurities could be estimated under the same plasma conditions. The estimated decay time of the Si impurities,  $\tau_{\text{Si}} = 0.12 \pm 0.01$  s, was found to be slightly longer than that of the B impurities,  $\tau_{\text{B}} = 0.09 \pm 0.01$  s.

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The study of the atomic number ( $Z$ ) dependence of the impurity transport in magnetically confined fusion plasmas is necessary to understand whether turbulent or neoclassical transport is dominant in plasmas. In general, the turbulent-dominant impurity transport does not exhibit a  $Z$ -dependence [1]. On the other hand, the neoclassical impurity transport does exhibit such a  $Z$ -dependence. An outstanding example of the contribution of the neoclassical transport is the impurity accumulation [2]. Recently, we demonstrated the applicability of the tracer-encapsulated solid pellet (TESPEL) [3] containing a compound tracer for a simultaneous study of the behaviors of different impurities [4]. Following this applicability demonstration, we report here that the simultaneous observation of behaviors of different impurities, which were locally deposited in the core region of the plasma under the same plasma conditions, has been achieved in the Large Helical Device (LHD).

Figure 1 shows the LHD discharge (#169088) waveform summary for this study. The TESPEL (with an outer diameter of  $900 \mu\text{m}$  and a polystyrene ( $-\text{CH}(\text{C}_6\text{H}_5)\text{CH}_2-$ ) shell thickness of  $120 \mu\text{m}$ ) containing silicon hexaboride ( $\text{SiB}_6$ ) powders was injected at the time of  $\sim 3.875$  s, as indicated by the black vertical dashed line. The target plasma was predominantly heated by tangential NBIs (NBI#2 and NBI#3) but also by perpendicular NBIs (NBI#4 and

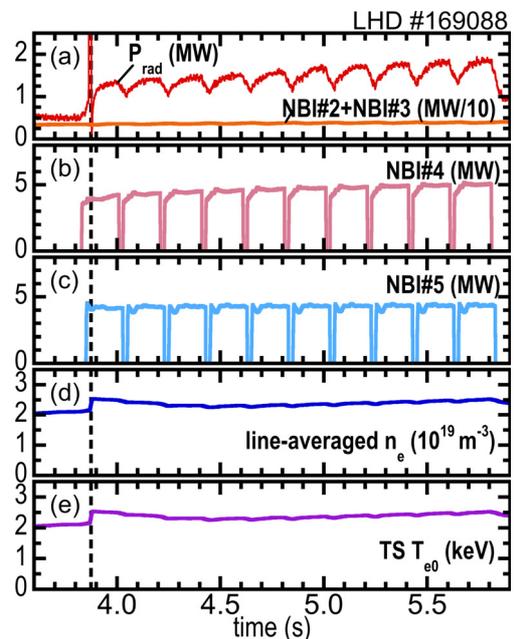


Fig. 1 Temporal evolutions of (a) the plasma radiation power and the tangential NBI power, (b) the perpendicular NBI#4 power, (c) the perpendicular NBI#5 power, (d) the line-averaged electron density, and (e) the central electron temperature. The TESPEL injection time, about 3.875 s, is indicated by a black vertical dashed line.

NBI#5). Here, the modulated (180 ms on and 20 ms off) NBI#5 was used as a probe beam for the charge-exchange spectroscopy (CX S) diagnostic for the boron (B) measurement. As shown in Fig. 1, the line-averaged electron density,  $n_{e\_bar}$ , which was about  $2 \times 10^{19} \text{ m}^{-3}$  before the TESPEL injection, was increased by the TESPEL injection. Subsequently, the increased  $n_{e\_bar}$  was decreased

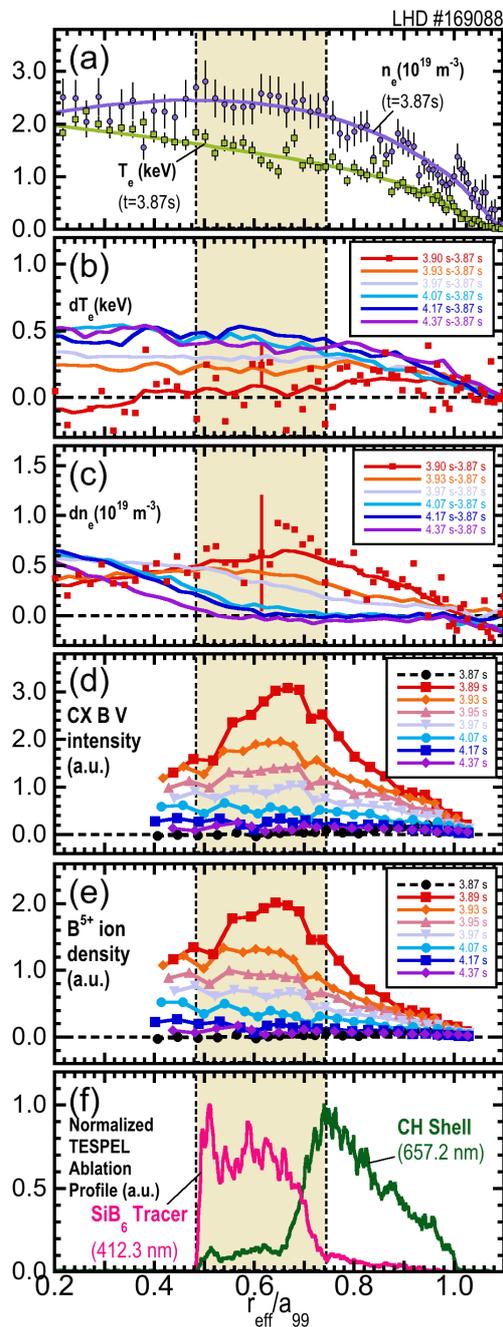


Fig. 2 Radial profiles of (a) the electron density and temperature just before the TESPEL injection, (b) the electron temperature variation, (c) the electron density variation, (d) the CX B V intensity, (e) the  $B^{5+}$  ion density, and (f) the normalized TESPEL ablation emissions. The TESPEL injection time is about 3.875 s. A typical error bar is shown in panels (b) and (c).

slightly, without anyhow recovering its pre-injection level. The central electron temperature,  $T_{e0}$ , also seemed to be increased by the TESPEL injection. However, since the increment of  $T_e$  was observed over a wide range (see Fig. 2 (b)). The baseline  $n_e$  and  $T_e$  profiles, which were measured with a Thomson scattering system [5], are shown in Fig. 2 (a), this can be explained in terms of the addition of NBI#4 and NBI#5, which were added almost at the same time as the TESPEL injection. The radial profile of the light emissions from the ablating  $SiB_6$ -TESPEL is shown in Fig. 2 (f). The dark green line shows the emissions measured with a photomultiplier tube (PMT) through an optical filter with a central wavelength,  $\lambda_{center}$ , of 657.2 nm and a full width half maximum (FWHM) of 1.2 nm; these provide information about  $H\alpha$  ( $\lambda = 656.3 \text{ nm}$ ) from the CH shell. Additionally, the magenta line shows the emissions measured with the PMT through an optical filter with  $\lambda_{center} = 412.3 \text{ nm}$  and FWHM = 1.1 nm; these provide information about Si II ( $\lambda = 413.09 \text{ nm}$ ) and B II ( $\lambda = 412.19 \text{ nm}$ ) from the  $SiB_6$  tracer. The CH shell ablation was observed in the  $r_{eff}/a_{99}$  range from 0.66 to 1.0 (the signal in the  $r_{eff}/a_{99}$  range from 0.48 to 0.66 can be considered as the contribution of the continuum radiation). Here,  $r_{eff}$  is the averaged minor radius on a magnetic flux surface and  $a_{99}$  is the effective minor radius in which 99% of the plasma kinetic energy is confined, which is 0.63 m in this discharge. Furthermore, the emissions from the  $SiB_6$  tracer were observed in the  $r_{eff}/a_{99}$  range from 0.48 to 0.74. The difference in the ablation region between the CH shell and the  $SiB_6$  tracer reflects the TESPEL configuration. In this work,  $r_{eff}/a_{99} = 0$  and 1 are considered as the plasma center and boundary, respectively. As shown in Fig. 2 (e), the very high-density region of the  $B^{5+}$  ions that appears immediately after the  $SiB_6$ -TESPEL injection is in good agreement with the possible deposition region of

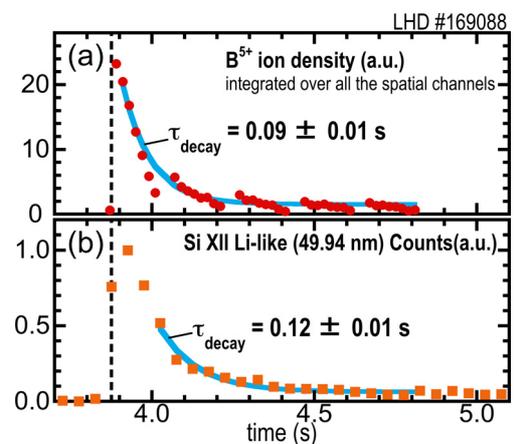


Fig. 3 Decay time estimated for (a) the spatially integrated  $B^{5+}$  ion density and (b) the Si XII Li-like emission intensity. The error bars for the data shown are within the size of each symbol.

the  $\text{SiB}_6$  tracer. It should be noted here that the pellet ablation profile is not the same as the pellet mass deposition profile. Here, the  $\text{B}^{5+}$  ion density,  $n_{\text{B}^{5+}}$ , was derived from the charge-exchange line of B V ( $\lambda = 494.5$  nm, shown in Fig. 2 (d)) and the beam density profile calculated using a beam attenuation code based on the measured  $n_e$  and  $T_e$  profiles. The hollow profile of  $n_{\text{B}^{5+}}$  relaxes with time, and the  $\text{B}^{5+}$  ions eventually disappear from the plasma. The peak position of the  $n_{\text{B}^{5+}}$  profile seems to move slightly inward. The  $n_e$  profile was also changed due to the  $\text{SiB}_6$ -TESPEL injection (see Fig. 2 (c)). The decay trend of the  $n_{\text{B}^{5+}}$  profile is a little similar to that of the  $n_e$  profile. However, it should be noted here that the  $n_e$  increment, especially inside the region with  $r_{\text{eff}}/a_{99} = 0.6$ , was affected also by NBI fueling. At the same time, Li-like emissions (Si XII, 49.94 nm) from the highly ionized silicon (Si) impurities were also observed with the EUV spectrometer, SOXMOS [6]. Thus, we could estimate the decay times of those impurities under the same plasma conditions. As shown in Fig. 3, the estimated global decay time of the Si impurities,  $\tau_{\text{Si}} = 0.12 \pm 0.01$  s is slightly longer than that of

the B impurities,  $\tau_{\text{B}} = 0.09 \pm 0.01$  s. Here, small variations in the temporal behavior of the spatially integrated  $n_{\text{B}^{5+}}$  in response to the modulation of the perpendicular NBIs are observed. This can be explained in terms of the residual boron resulting from the boronization, etc., but it has a negligible impact on the global decay trend of  $n_{\text{B}^{5+}}$ . These results indicate that the behaviors of impurities with different  $Z$  values ( $Z = 5$  and  $14$ ) that were locally deposited in the core region of the plasma under the same plasma conditions were successfully obtained.

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